Device Modeling Report

COMPONENTS: MOSFET: OPERATIONAL AMPLIFIER

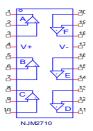
PART NUMBER:NJM2710

MANUFACTURER: NEW JAPAN RADIO CO.,LTD



Bee Technologies Inc.

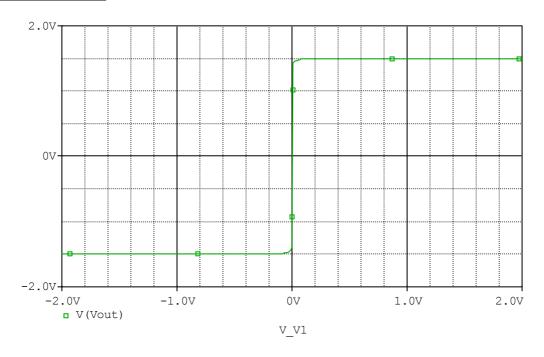
Spice Model

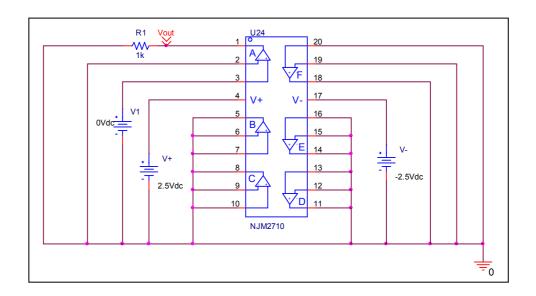


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PART NUMBER:NJM2710
 MANUFACTURER: NEW JAPAN RADIO
 All Rights Reserved Copyright (c) Bee Technologies Inc. 2007
.Subckť NJM2710 AOUT ÁIN- AIN+ V+ BOUT BIN- BIN+ COUT CIN- CIN+
+ DOUT DIN- DIN+ EOUT EIN- EIN+ V- FOUT FIN- FIN+
X U1
         AIN+ AIN- V+ V- AOUT NJM2710_ME
         BIN+ BIN- V+ V- BOUT NJM2710 ME
CIN+ CIN- V+ V- COUT NJM2710 ME
DIN+ DIN- V+ V- DOUT NJM2710 ME
EIN+ EIN- V+ V- EOUT NJM2710 ME
  U2
  -U3
  Ū4
  U5
  <sup>-</sup>U6
         FIN+ FIN- V+ V- FOUT NJM2710 ME
.ends NJM2710
.subckt NJM2710_ME 1 2 3 4 5
     11 12 9.00E-12
 С1
      6 7 164.00E-13
 c2
      5 53 dy
 dc
 de 54 5 dy
 dlp 90 91 dx
 dln 92 90 dx
      4 3 dx
 dp
 egnd 99 0 poly(2) (3,0) (4,0) 0 .5 .5
     7 99 poly(5) vb vc vè vlp vln 0 6.6296E3 -1E3 1E3 6E3 -6E3 6 0 11 12 33E-3
 ga
 gcm 0 6 10 99 33E-6
 iee 3 10 dc 7.8040E-3
 hlim 90 0 vlim 1K
     11 2 13 qx1
 q1
     12 1 14 qx2
6 9 100.00E3
 q2
r2
 rc1
      4 11 29.473
 rc2
      4 12 29.473
     13 10 22.830
14 10 22.830
 re1
 re2
 ree 10 99 25.628E3
    8 5 50
2 7 99 <u>25</u>
ro1
 ro2
      3 4 155.29
      9 0 dc 0
 νb
      3 53 dc 1.7979
 VC
 ve 54 4 dc 1.7979
 vlim 7 8 dc 0
 vlp 91 0 dc 20
 vln 0 92 dc 20
.model dx D(ls=800.00E-18)
.model dy D(ls=800.00E-18 Rs=1m)
.model qx1 PNP(Is=800.00E-18 Bf=1.7967E3)
.model qx2 PNP(ls=836.3700E-18 Bf=2.1697E3)
.ends
*$
```

Output Voltage Swing

Simulation result

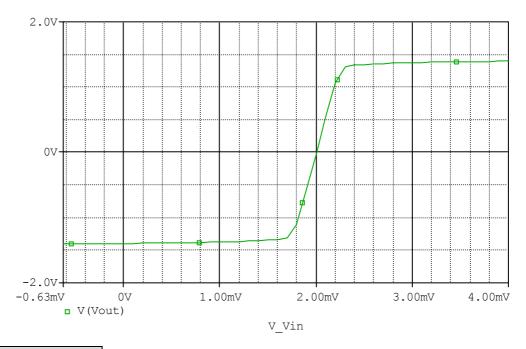


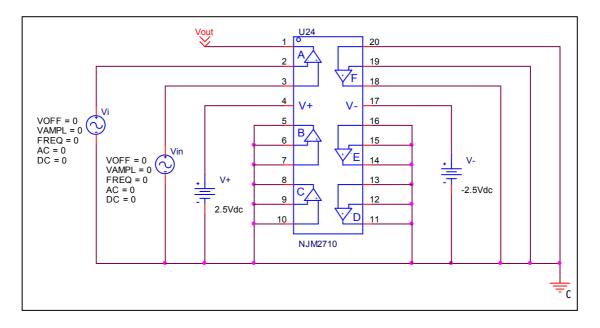


Output Voltage Swing	Measurement	Simulation	%Error
+Vout(V)	1.500	1.499	-0.067
-Vout(V)	-1.500	-1.499	-0.067

Input Offset Voltage

Simulation result



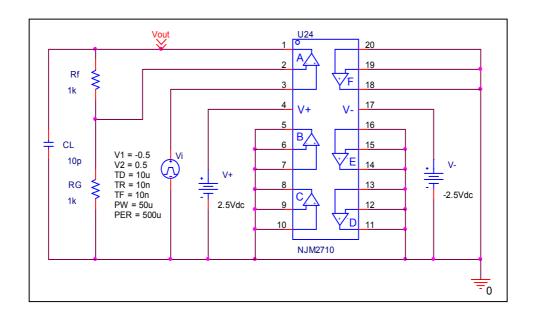


Vos	Measurem	ent	Simulatio	n	Error	
V05	2.000	mV	2.006	mV	-0.300	%

Slew Rate

Simulation result

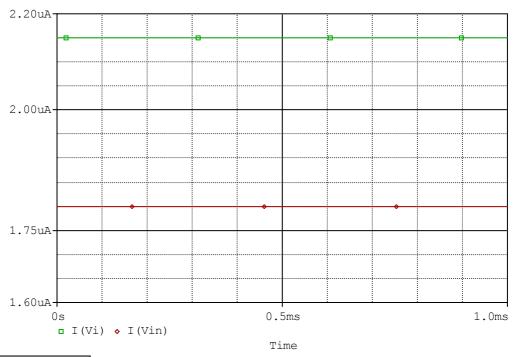


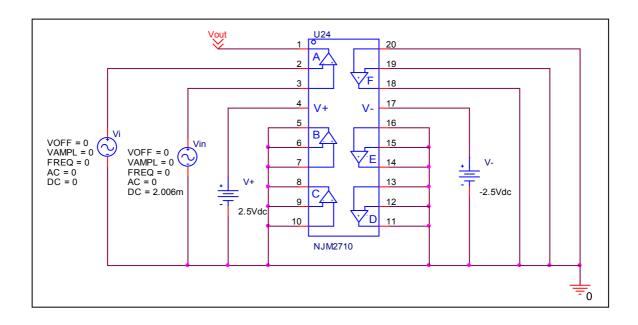


Slew	Measurement	Simulation	%Error
Rate(v/us)	260.000	254.552	-2.095

Input current lb, lbos

Simulation result

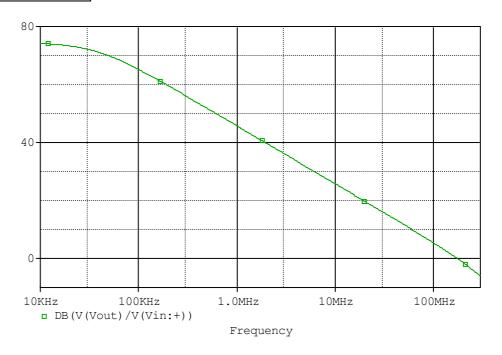


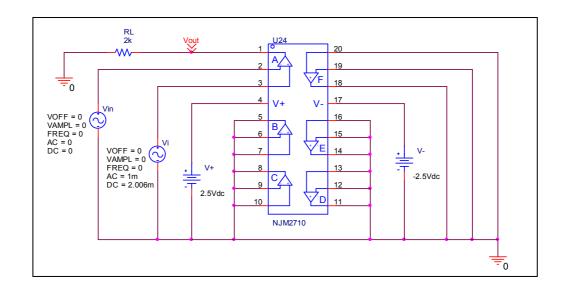


	Measurement	Simulation	%Error
lb(uA)	2.000	1.974	-1.300
lbos(nA)	350.000	351.615	0.461

Open Loop Voltage Gain vs. Frequency, Av-dc

Simulation result

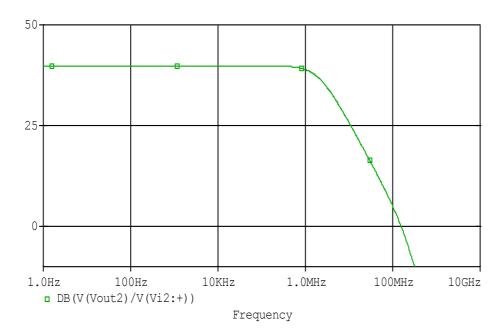




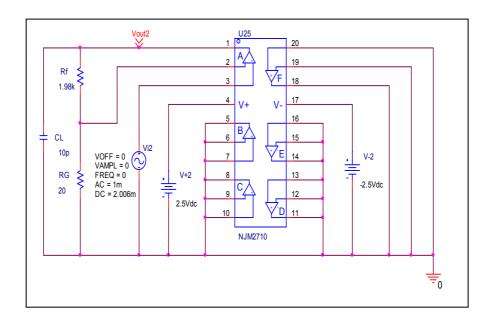
	Measurement	Simulation	%Error
Av-dc(dB)	75.000	74.129	1.161

Unity Gain Bandwidth

Simulation result



Evaluation circuit

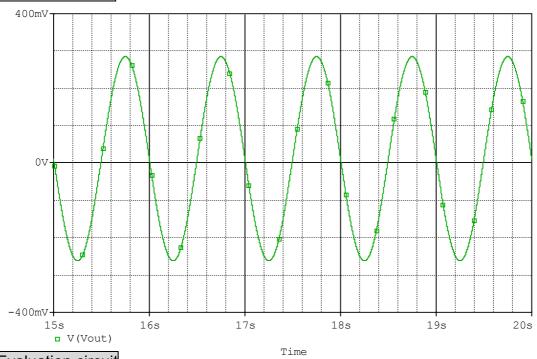


Comparison table

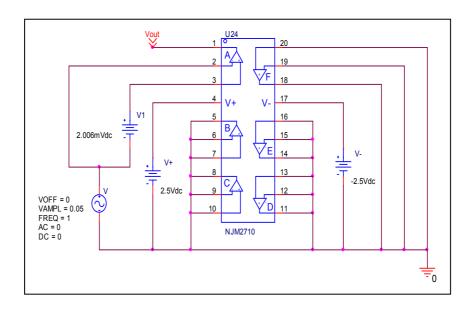
	Measurement	Simulation	%Error
f-0dB(MHz)	180.000	175.021	-2.766

Common-Mode Rejection Voltage gain

Simulation result



Evaluation circuit

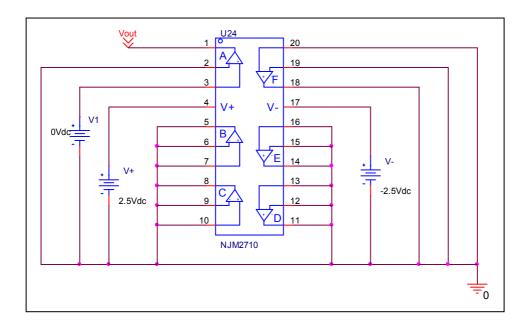


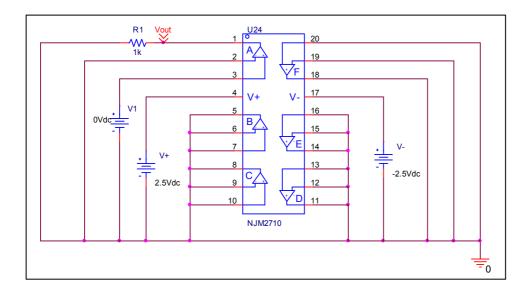
Common Mode Reject Ratio=5109.75/5.463=935.3377

CMRR(dB)	Measurement	Simulation	%Error
CWIKK(UB)	60.000	59.419	-0.968

Remark Output Voltage Swing

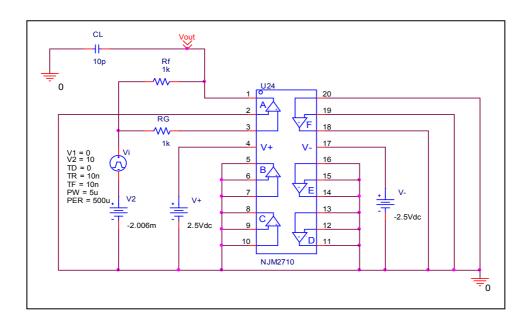
Before

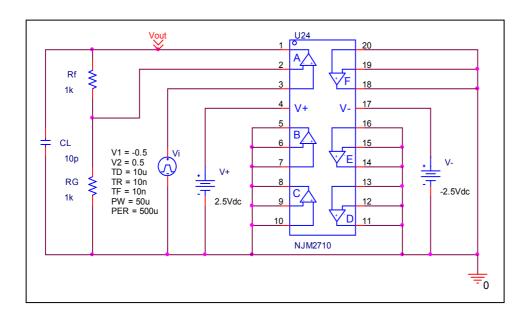




Remark Slew Rate

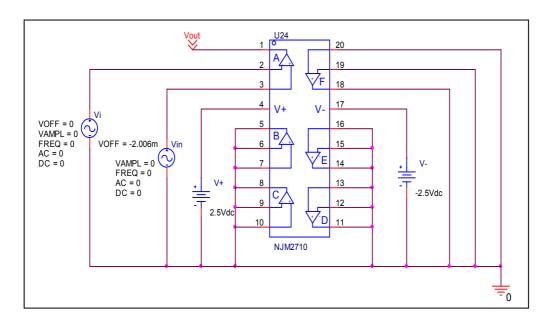
Before

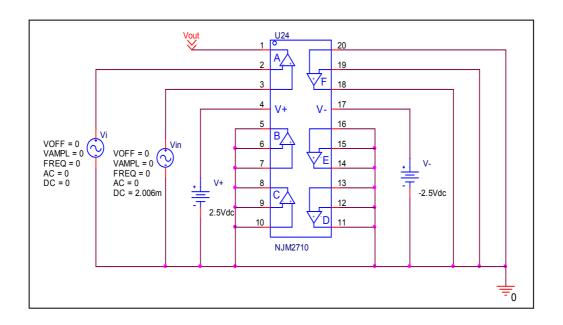




Remark Input current

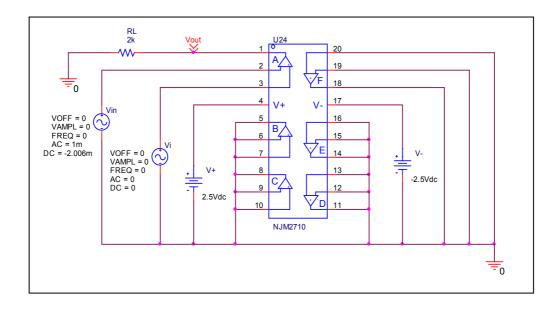
Before

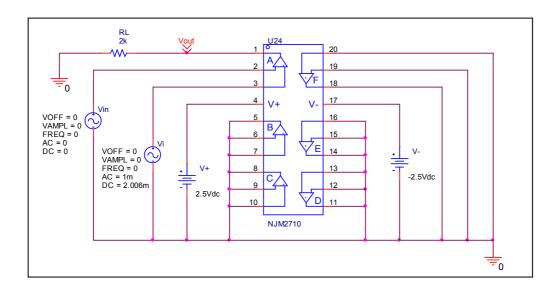




Remark Open Loop Voltage Gain vs. Frequency

Before





Remark Common-Mode Rejection Voltage gain

Before

